



NTE2076 Integrated Circuit 7-Segment Darlington Transistor Array ^w/Clamp Diode

Description:

The NTE2076 is constructed with a 7-circuit Darlington Transistor Array by a NPN Transistor and is a semi-conductor integrated circuit (IC) which can drive large electric current with very small input current.

Features:

- High Electric Voltage Endurance ($BV_{CEO} \geq 40V$)
- Large Electric Current Drive ($I_C (\text{max}) = 150\text{mA}$)
- Convenient for Practical Attachment
- Available to Drive with PMOS IC Output
- Clamp Diode Attached
- Wide Input Voltage Range ($-40V$ to $+40V$)
- Wide Operating Temperature Range ($T_A = -20^\circ$ to $+75^\circ\text{C}$)

Applications:

Attachment relay or printer drive, digit drive of LED and lamps indicator device, interface of MOS bipolar-logic IC, etc.

Absolute Maximum Ratings: ($T_A = -20^\circ$ to $+75^\circ\text{C}$ unless otherwise specified)

Voltage Between Collector and Emitter when Output is "High", V_{CEO} -0.5 to $+40V$
Collector Current when Output is "Low", each Current for a Circuit, I_C 150mA
Input Voltage, V_i -40 to $+40V$
Clamp Diode Positive-Direction Current, I_f 150mA
Clamp Diode Negative-Direction Voltage, V_a $40V$
Power Consumption ($T_A = +25^\circ\text{C}$), P_d $1.47W$
Operating Ambient Temperature Range, T_{opr} -20° to $+75^\circ\text{C}$
Storage Temperature Range, T_{stg} -55° to $+125^\circ\text{C}$

Electrical Characteristics: ($T_A = -20^\circ$ to $+75^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Output Voltage	V_O		0	—	40	V
Collector Current	I_C	Duty Cycle 40% or less (each current for a circuit)	0	—	150	mA
"High" Input Voltage	$V_{\text{"H"}}$	$I_C = 150\text{mA}$	7	—	35	V
"Low" Input Voltage	$V_{\text{"L"}}$	$I_{O(\text{Leak})} = 50\mu\text{A}$	0	—	1	V

Pin Connection Diagram

